



NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856W BC858W
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

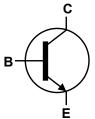
Mechanical Data

- Case: SOT323
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.006 grams (Approximate)

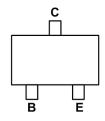








Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

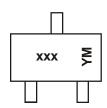
| Product | Compliance | Marking | Reel Size (inches) | Quantity per Reel |
|--------------|------------|---------|--------------------|-------------------|
| BC846AW-7-F | AEC-Q101 | K1Q | 7 | 3,000 |
| BC846BW-7-F | AEC-Q101 | K1R | 7 | 3,000 |
| BC846BWQ-7-F | Automotive | K1R | 7 | 3,000 |
| BC846BW-13-F | AEC-Q101 | K1R | 13 | 10,000 |
| BC847AW-7-F | AEC-Q101 | K1Q | 7 | 3,000 |
| BC847BW-7-F | AEC-Q101 | K1R | 7 | 3,000 |
| BC847BW-13-F | AEC-Q101 | K1R | 13 | 10,000 |

| Product | Compliance | Marking | Reel Size (inches) | Quantity per Reel |
|---------------|------------|---------|--------------------|-------------------|
| BC847BWQ-13-F | Automotive | K1R | 13 | 10,000 |
| BC847CW-7-F | AEC-Q101 | K1M | 7 | 3,000 |
| BC847CW-13-F | AEC-Q101 | K1M | 13 | 10,000 |
| BC847CWQ-7-F | Automotive | K1M | 7 | 3,000 |
| BC848AW-7-F | AEC-Q101 | K1Q | 7 | 3,000 |
| BC848BW-7-F | AEC-Q101 | K1R | 7 | 3,000 |
| BC848CW-7-F | AEC-Q101 | K1M | 7 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



xxx = Product Type Marking Code
(Please see Ordering Information)
YM = Date Code Marking
Y or Y = Year (ex: A = 2013)
M or M = Month (ex: 9 = September)

Date Code Key

| Year | 2010 | | 2011 | 2012 | | 2013 | 2014 | | 2015 | 2016 | | 2017 |
|-------|------|-----|------|------|-----|------|------|-----|------|------|-----|------|
| Code | X | | Υ | Z | | Α | В | | С | D | | Е |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteri | stic | Symbol | Value | Unit |
|------------------------------|--------------|------------------|-------|------|
| | BC846 | | 80 | |
| Collector-Base Voltage | BC847 | V_{CBO} | 50 | V |
| | BC848 | | 30 | |
| | BC846 | | 65 | |
| Collector-Emitter Voltage | BC847 | V _{CEO} | 45 | V |
| | BC848 | | 30 | |
| Emitter-Base Voltage | BC846, BC847 | V | 6 | V |
| Emitter-Base voltage | BC848 | V _{EBO} | 5 | V |
| Continuous Collector Current | | Ic | 100 | mA |
| Peak Collector Current | | Ісм | 200 | mA |
| Peak Base Current | | I _{BM} | 200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|-----------------------------------|----------------|------|------|
| Power Dissipation | (Note 6) | P _D | 200 | mW |
| Thermal Resistance, Junction to Ambient (Note 6) | | $R_{	heta JA}$ | 625 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C | |

ESD Ratings (Note 7)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | ٧ | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

Notes:

^{6.} For a device mounted on minimum recommended pad layout 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | | Symbol | Min | Тур | Max | Unit | Test Condition | |
|----------------------------------|------------------|------|----------------|----------------------|-----|-----|-----|--|--|--|
| | | Е | 3C846 | | 80 | | | | | |
| Collector-Base Breakdown Voltage | | Е | BC847 | BV _{CBO} | 50 | _ | _ | V | I _C = 100μA | |
| | | Е | BC848 | | 30 | | | | | |
| | | Е | 3C846 | | 65 | | | | | |
| Collector-Emitter Breakdown V | /oltage (Note 8) | E | BC847 | BV _{CEO} | 45 | _ | _ | V | I _C = 10mA | |
| | | E | 3C848 | | 30 | | | | | |
| Emitter-Base Breakdown Volta | ane | BC84 | 46, BC847 | BV _{EBO} | 6 | | _ | V | I _E = 100μA | |
| Limiter-base Breakdown Volta | | E | 3C848 | DAFRO | 5 | | | V | ΙΕ – 100μΑ | |
| | | | Α | | 110 | 180 | 220 | | | |
| DC Current Gain (Note 8) | Current Gain Gr | oup | В | h _{FE} | 200 | 290 | 450 | _ | $V_{CE} = 5.0V, I_{C} = 2.0mA$ | |
| | | | С | | 420 | 520 | 800 | | | |
| Collector Cutoff Current | | | | I _{CBO} | _ | _ | 20 | nA | V _{CB} = 30V | |
| Collector Cutoff Current | | | | | | | 5 | μA | V _{CB} = 30V, T _A = +150°C | |
| Collector-Emitter Saturation Vo | oltago (Noto 9) | | | V _{CE(sat)} | | 90 | 250 | mV | $I_C = 10mA, I_B = 0.5mA$ | |
| Collector-Emitter Saturation vo | ollage (Note 6) | | | | _ | 200 | 600 | 1110 | I _C = 100mA, I _B = 5.0mA | |
| Base-Emitter Turn-On Voltage | (Note 9) | | | ., | 580 | 660 | 700 | mV | I_C = 2mA, V_{CE} = 5V | |
| base-Emiller rum-On voltage | (Note 6) | | | V _{BE(on)} | _ | | 770 | IIIV | I _C = 10mA, V _{CE} = 5V | |
| Base-Emitter Saturation Voltage | ro (Noto 9) | | | \/· | | 700 | | mV | $I_C = 10$ mA, $I_B = 0.5$ mA | |
| Base-Emiller Saluration Voltag | ge (Note 6) | | | V _{BE(sat)} | _ | 900 | | IIIV | I _C = 100mA, I _B = 5mA | |
| Output Capacitance | | | | C _{obo} | _ | 3 | 4.5 | pF | V _{CB} = 10V, f = 1.0MHz | |
| Transition Frequency | | | f _T | 100 | 300 | _ | MHz | $V_{CE} = 5V, I_{C} = 10mA,$ f = 100MHz | | |
| Noise Figure | | | NF | _ | _ | 10 | dB | V_{CE} = 5V, I_{C} = 200 μ A R_{S} = 2k Ω , f = 1kHz Δf = 200Hz | | |

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

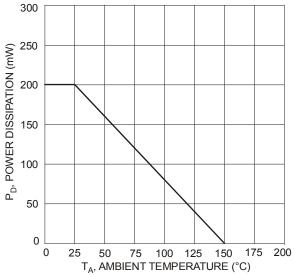


Figure 1 Power Dissipation vs. Ambient Temperature

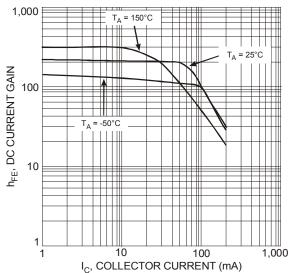


Figure 3 Typical DC Current Gain vs. Collector Current

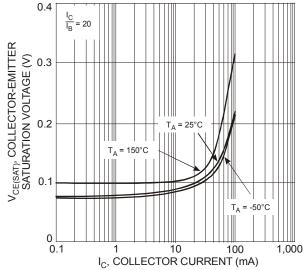


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

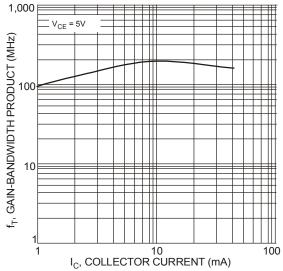
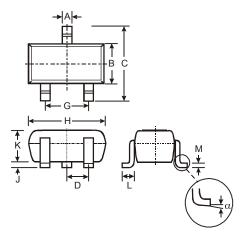


Figure 4 Typical Gain-Bandwidth Product vs. Collector Current



Package Outline Dimensions

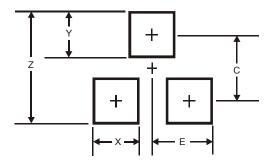
 $Please\ see\ AP02002\ at\ http://www.diodes.com/datasheets/ap02002.pdf\ for\ latest\ version.$



| SOT323 | | | | | | | |
|--------|--------|---------|------|--|--|--|--|
| Dim | Min | Max | Тур | | | | |
| Α | 0.25 | 0.40 | 0.30 | | | | |
| В | 1.15 | 1.35 | 1.30 | | | | |
| C | 2.00 | 2.20 | 2.10 | | | | |
| D | - | - | 0.65 | | | | |
| G | 1.20 | 1.40 | 1.30 | | | | |
| Н | 1.80 | 2.20 | 2.15 | | | | |
| 7 | 0.0 | 0.10 | 0.05 | | | | |
| K | 0.90 | 1.00 | 1.00 | | | | |
| L | 0.25 | 0.40 | 0.30 | | | | |
| M | 0.10 | 0.18 | 0.11 | | | | |
| α | 0° | 8° | _ | | | | |
| All | Dimens | ions in | mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.8 |
| Х | 0.7 |
| Υ | 0.9 |
| С | 1.9 |
| E | 1.0 |



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